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### **BC182L**

### **NPN General Purpose Amplifier**

- This device is designed for general purpose amplifier application at collector currents to 100mA.
- Sourced from process 10.



1. Emitter 2. Collector 3. Base

### Absolute Maximum Ratings $T_C=25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Value	Units
V <sub>CEO</sub>	Collector-Emitter Voltage	50	V
V <sub>CBO</sub>	Collector-Base Voltage	60	V
V <sub>EBO</sub>	Emitter-Base Voltage	6	V
I <sub>C</sub>	Collector Current - Continuous	100	mA
T <sub>J,</sub> T <sub>STG</sub>	Storage Junction Temperature Range	- 55 ~ 150	°C

### Electrical Characteristics $T_C=25^{\circ}C$ unless otherwise noted

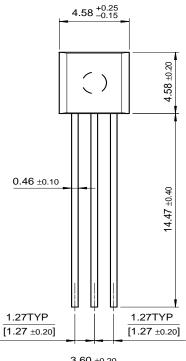
Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units	
Off Chara	Off Characteristics						
V <sub>(BR)CEO</sub>	Collector-Emitter Breakdown Voltage	$I_C = 2mA, I_B = 0$ 50				V	
V <sub>(BR)CBO</sub>	Collector-Base Breakdown Voltage	$I_C = 10\mu A, I_E = 0$	60			V	
V <sub>(BR)EBO</sub>	Emitter-Base Breakdown Voltage	$I_E = 100\mu A, I_C = 0$	6			V	
I <sub>CBO</sub>	Collector Cut-off Current	$V_{CB} = 50V, V_{BE} = 0$			15	nA	
I <sub>EBO</sub>	Emitter-Base Leakage Current	$V_{EB} = 4V, I_{E} = 0$			15	nA	
On Chara	On Characteristics						
h <sub>FE</sub>	DC Current Gain	$V_{CE} = 5V, I_{C} = 10\mu A$ $V_{CE} = 5V, I_{C} = 2mA$ $V_{CE} = 5V, I_{C} = 100mA$	40 120 80		500		
V <sub>CE</sub> (sat)	Collector-Emitter Saturation Voltage	I <sub>C</sub> = 10mA, I <sub>B</sub> = 0.5mA I <sub>C</sub> = 100mA, I <sub>B</sub> = 5mA			0.25 0.6	V	
V <sub>BE</sub> (sat)	Base-Emitter Saturation Voltage	I <sub>C</sub> = 100mA, I <sub>B</sub> = 5mA			1.2	V	
V <sub>BE</sub> (on)	Base-Emitter On Voltage	$V_{CE} = 5V$ , $I_C = 2mA$	0.55		0.7	V	
Dynamic (	Characteristics				•		
f <sub>T</sub>	Current Gain Bandwidth Product	V <sub>CE</sub> = 5V, I <sub>C</sub> = 10mA, f = 100MHz 150				MHz	
C <sub>ob</sub>	Output Capacitance	V <sub>CE</sub> = 10V, I <sub>C</sub> = 0, f = 1MHz			5	pF	
h <sub>fe</sub>	Small Signal Current Gain	$V_{CE} = 5V$ , $I_C = 2mA$ , $f = 1KHz$	240		500		
NF	Noise Figure	$V_{CE} = 5V$ , $I_{C} = 0.2$ mA $R_{S} = 2$ K $\Omega$ , $f = 1$ KHz, BW = 200Hz			10	dB	

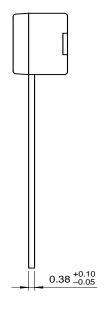
### Thermal Characteristics $T_A=25$ °C unless otherwise noted

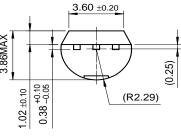
Symbol	Parameter	Max.	Units
P <sub>D</sub>	Total Device Dissipation @T <sub>A</sub> =25°C	350	mW
_	Derate above 25°C	2.8	mW/°C
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient 357		mW/°C
$R_{\theta JC}$	Thermal Resistance, Junction to Case	125	°C/W

# **Package Dimensions**

TO-92







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